



### **30V P-Channel Enhancement Mode Mosfet**

Voltage

-30 V

Current

-3.8 A

#### **Features**

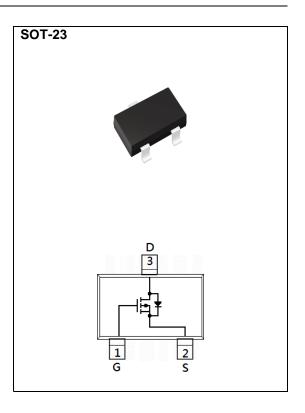
- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-3.8A<65m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-2.6A<80m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20		
Continuous Drain Current(Note 4)		ID	-3.8	А	
Pulsed Drain Current <sup>(Note 1)</sup>		I <sub>DM</sub>	-15.2		
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3,4)</sup>		$R_{ heta JA}$	100	°C/W	





### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	1	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-1.36	-2.1	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-3.8A	-	52	65	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2.6A	-	66	80	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic <sup>(Note 5)</sup>						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-3.8A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	12	-	nC
Gate-Source Charge	Qgs		-	1.7	-	
Gate-Drain Charge	$Q_gd$		-	2.3	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V,	-	528	-	pF ns
Output Capacitance	Coss		-	63	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	48	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}\text{=-}15V,\ I_{D}\text{=-}3.8A,$ $V_{GS}\text{=-}10V,$ $R_{G}\text{=}6\Omega^{(Note\ 1,2)}$	-	5	-	
Turn-On Rise Time	tr		-	33	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	27	1	
Turn-Off Fall Time	tf		-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	la				1 5	_
Diode Forward Current	Is		-	-	-1.5	А
Diode Forward Voltage	V <sub>SD</sub>	Is=-1A, V <sub>GS</sub> =0V	-	-0.76	-1.2	V

### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

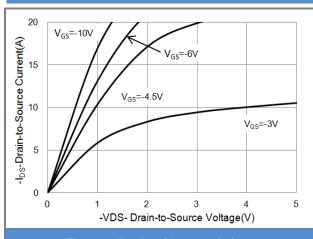
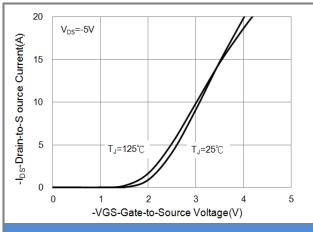


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

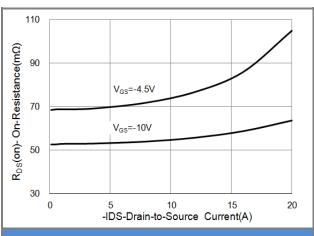


Fig.3 On-Resistance vs. Drain Current

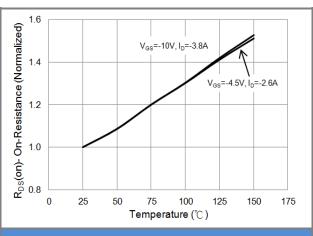
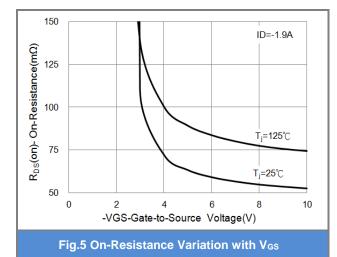
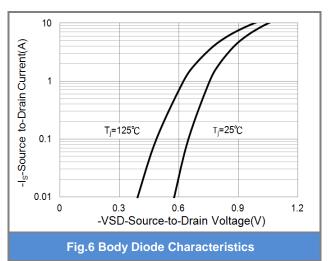


Fig.4 On-Resistance vs. Junction temperature









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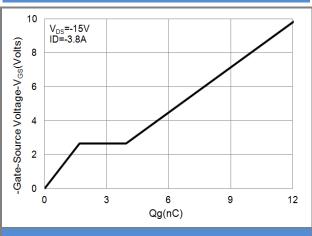


Fig.7 Gate-Charge Characteristics

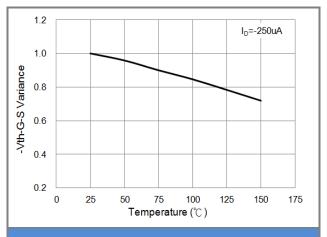


Fig.8 Threshold Voltage Variation with Temperature

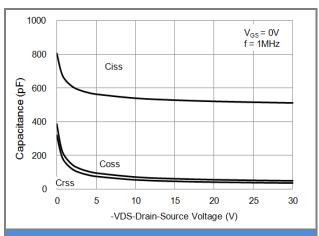


Fig.9 Capacitance vs. Drain-Source Voltage

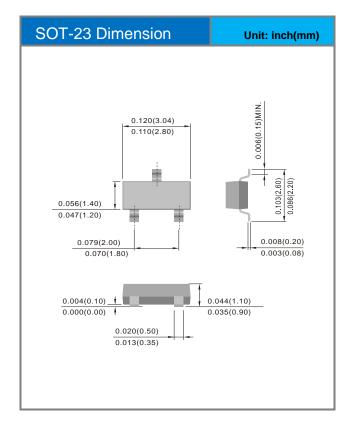


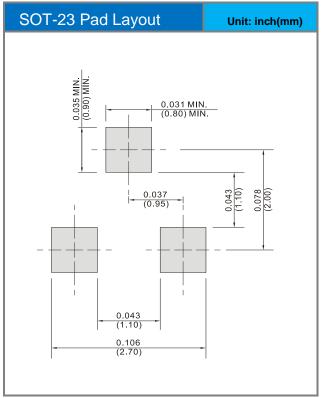


### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJA3407-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A07	Halogen free RoHS compliant

### **Packaging Information & Mounting Pad Layout**









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